

FX70KMJ-03

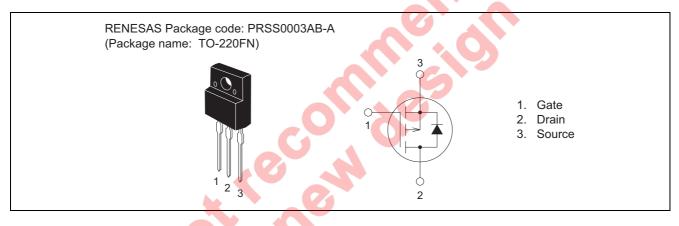
High-Speed Switching Use Pch Power MOS FET

> REJ03G1455-0200 (Previous: MEJ02G0270-0101) Rev.2.00 Aug 07, 2006

Features

- Drive voltage : 4 V
- V_{DSS} : -30 V
- $r_{DS(ON)(max)}$: 12.3 m Ω
- I_D: -70 A
- Integrated Fast Recovery Diode (TYP.) : 70 ns
- Viso : 2000 V

Outline



Applications

Motor control, Lamp control, Solenoid control, DC-DC converters, etc.

Maximum Ratings

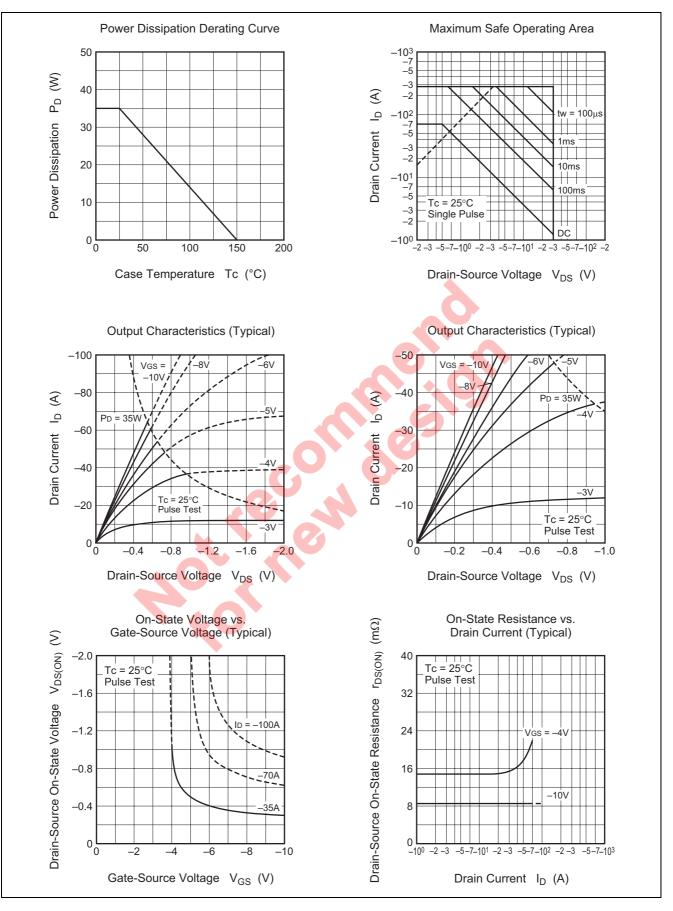
				$(Tc = 25^{\circ}C)$
Parameter	Symbol	Ratings	Unit	Conditions
Drain-source voltage	V _{DSS}	-30	V	$V_{GS} = 0 V$
Gate-source voltage	V _{GSS}	±20	V	$V_{DS} = 0 V$
Drain current	ID	-70	A	
Drain current (Pulsed)	I _{DM}	-280	A	
Avalanche drain current (Pulsed)	I _{DA}	-70	A	L = 10 μH
Source current	ls	-70	A	
Source current (Pulsed)	I _{SM}	-280	A	
Maximum power dissipation	PD	35	W	
Channel temperature	Tch	- 55 to +150	°C	
Storage temperature	Tstg	- 55 to +150	°C	
Isolation voltage	Viso	2000	V	AC for 1 minute,
				Terminal to case
Mass		2.0	g	Typical value



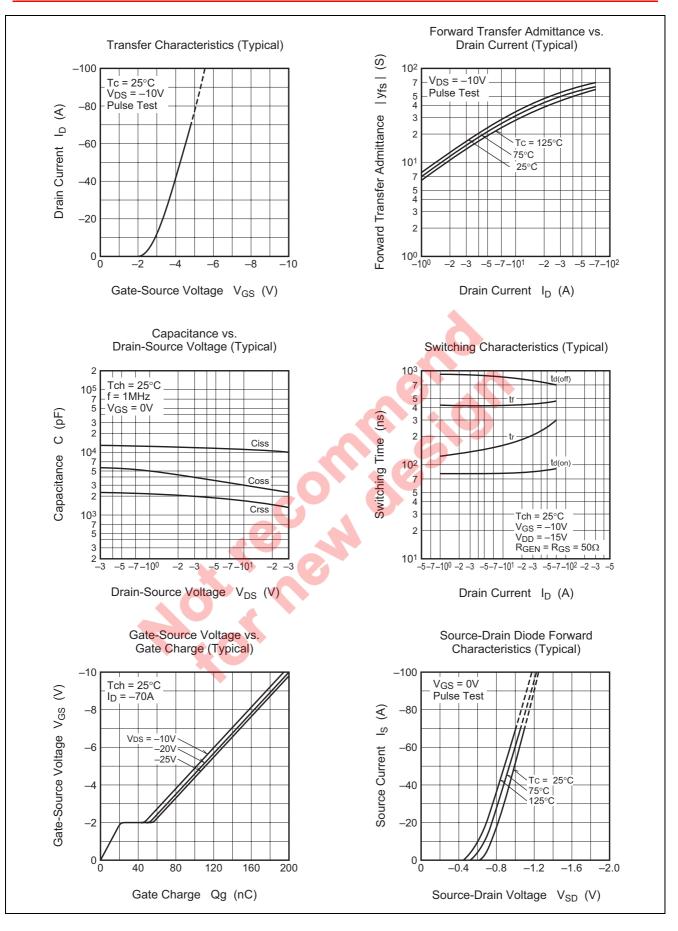
Electrical Characteristics

						$(Tch = 25^{\circ}C)$
Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain-source breakdown voltage	V _{(BR)DSS}	-30	—	—	V	$I_D = -1 \text{ mA}, V_{GS} = 0 \text{ V}$
Gate-source leakage current	I _{GSS}	—	—	±0.1	μA	V_{GS} = ±20 V, V_{DS} = 0 V
Drain-source leakage current	I _{DSS}	—	—	-0.1	mA	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$
Gate-source threshold voltage	V _{GS(th)}	-1.3	-1.8	-2.3	V	$I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$
Drain-source on-state resistance	r _{DS(ON)}	—	10.0	12.3	mΩ	$I_D = -35 \text{ A}, V_{GS} = -10 \text{ V}$
Drain-source on-state resistance	r _{DS(ON)}	—	19	25	mΩ	$I_D = -26 \text{ A}, V_{GS} = -4 \text{ V}$
Drain-source on-state voltage	V _{DS(ON)}	—	-0.35	-0.43	V	$I_D = -35 \text{ A}, V_{GS} = -10 \text{ V}$
Forward transfer admittance	y _{fs}	—	55.8	_	S	$I_D = -35 \text{ A}, V_{DS} = -10 \text{ V}$
Input capacitance	Ciss	—	11140	_	pF	$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = 0 \text{ V},$
Output capacitance	Coss	—	2300	_	pF	f = 1MHz
Reverse transfer capacitance	Crss	—	1000	_	pF	
Turn-on delay time	t _{d(on)}	—	85	_	ns	$V_{DD} = -15 \text{ V}, \text{ I}_{D} = -35 \text{ A},$
Rise time	tr	—	228	—	ns	$V_{GS} = -10 V$,
Turn-off delay time	t _{d(off)}	—	751		ns	$R_{GEN} = R_{GS} = 50 \ \Omega$
Fall time	t _f	—	360	—	ns	
Source-drain voltage	V _{SD}	—	-1.0	-1.5	V	$I_{S} = -35 \text{ A}, V_{GS} = 0 \text{ V}$
Thermal resistance	R _{th(ch-c)}	—	—	3.57	°C/W	Channel to case
Reverse recovery time	trr	—	70		ns	l _S = −35 A, d _{is} /d _t = 50 A/μs

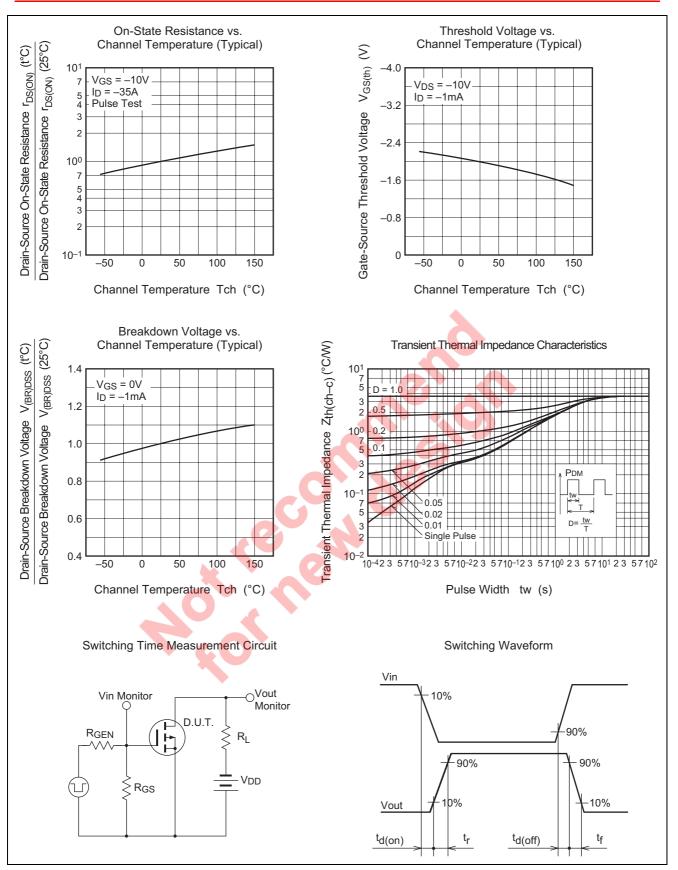
Performance Curves





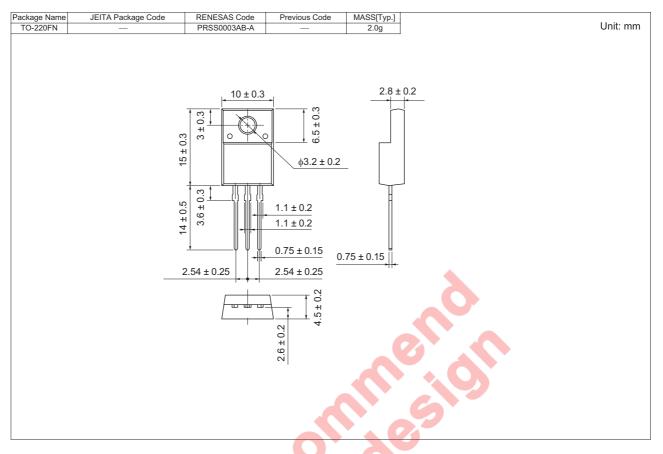








Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Plastic Magazine (Tube)	50) Type name	FX70KMJ-03
Lead form	Plastic Magazine (Tube)	50	Type name – Lead forming code	FX70KMJ-03-A8

Note: Please confirm the specification about the shipping in detail.

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